Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

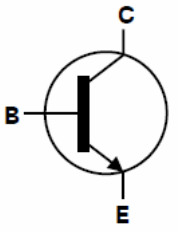
- BV_{CEO} > 45V
- I_C = 0.5A Continuous Collector Current
- I_{CM} = 1A Peak Pulse Current
- Complementary PNP Types: BC807-xxQ
- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- For Switching and AF Amplifier Applications
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The BC817-16Q /-25Q/-40Q are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

Mechanical Data

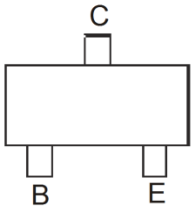
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight 0.008 grams (Approximate)

SOT23

Top View



Device Symbol



Top View
Pin-Out

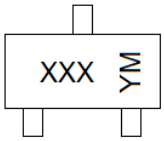
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
BC817-16Q-7-F	Automotive	K6A	7	8	3,000
BC817-25Q-7-F	Automotive	K6B	7	8	3,000
BC817-40Q-7-F	Automotive	K6C	7	8	3,000
BC817-40Q-13-F	Automotive	K6C	13	8	10,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT23



XXX = Product Type Marking Code (See Ordering Information)
YM = Date Code Marking
Y or $\overline{Y}$ = Year (ex: I = 2021)
M = Month (ex: 9 = September)

Date Code Key

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2033
Code	I	J	K	L	M	N	O	P	R	S	T	U

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Collector Current	I_C	0.5	A
Peak Pulse Collector Current (single pulse)	I_{CM}	1.0	A
Peak Pulse Base Current (single pulse)	I_{BM}	200	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

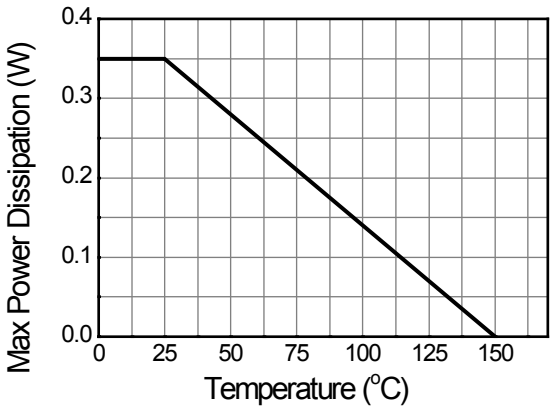
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	310	mW
	(Note 6)		350	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	403	°C/W
	(Note 6)		357	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{\theta JL}$	350	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-65 to +150	°C

ESD Ratings (Note 8)

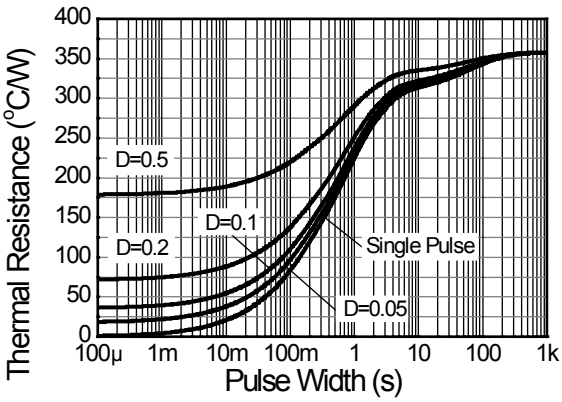
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note 5, except mounted on 15mm x 15mm 1oz copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

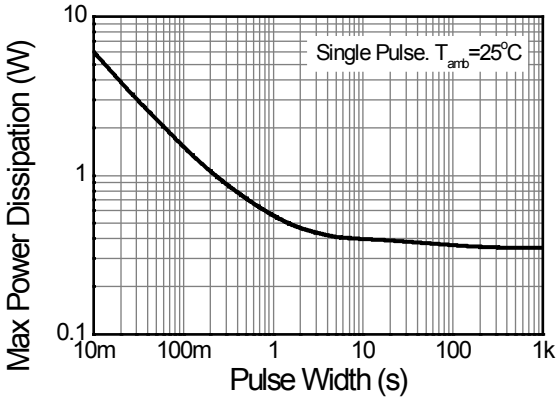
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



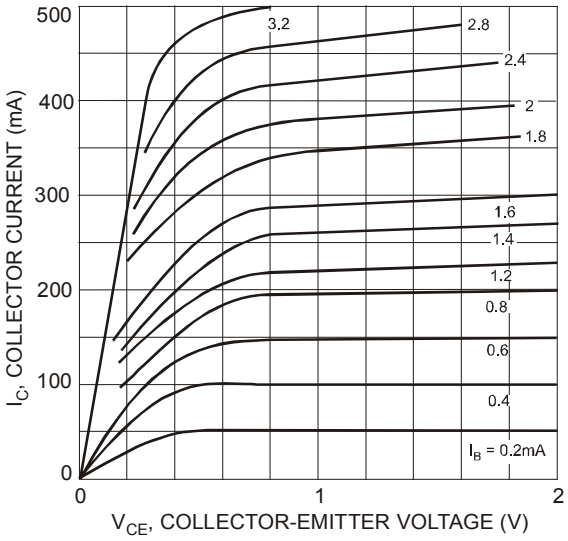
Pulse Power Dissipation

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

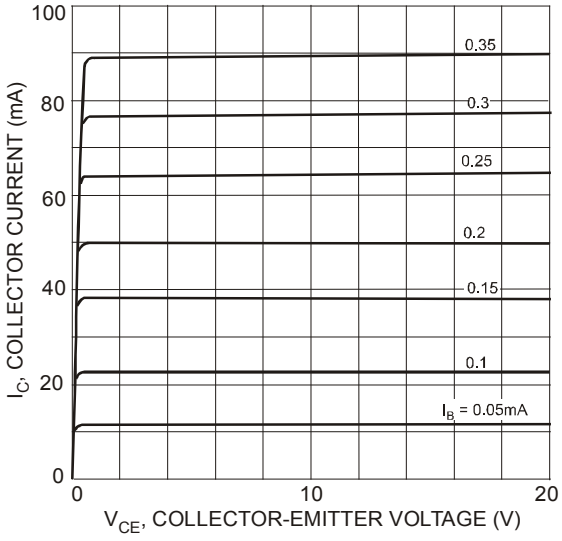
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV_{CBO}	50	—	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Note 9)		BV_{CEO}	45	—	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage		BV_{EBO}	5	—	—	V	I_C = 100µA
Collector-Emitter Cut-Off Current		I_{CES}	—	—	100 5.0	nA µA	V_{CE} = 45V V_{CE} = 25V, T_J = +150°C
Emitter-Base Cut-Off Current		I_{EBO}	—	—	100	nA	V_{EB} = 5.0V
DC Current Gain (Note 9)	BC817-16Q BC817-25Q BC817-40Q	h_{FE}	100 160 250	—	250 400 600	—	V_{CE} = 1.0V, I_C = 100mA
	BC817-16Q BC817-25Q BC817-40Q		60 100 170		—		V_{CE} = 1.0V, I_C = 300mA
Collector-Emitter Saturation Voltage (Note 9)		$V_{CE(sat)}$	—	—	0.7	V	I_C = 500mA, I_B = 50mA
Base-Emitter Voltage (Note 9)		V_{BE}	—	—	1.2	V	V_{CE} = 1.0V, I_C = 300mA
Transition frequency		f_T	100	—	—	MHz	V_{CE} = 5.0V, I_C = 10mA, f = 50MHz
Collector-Base Capacitance		C_{CBO}	—	—	12	pF	V_{CB} = 10V, f = 1.0MHz

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

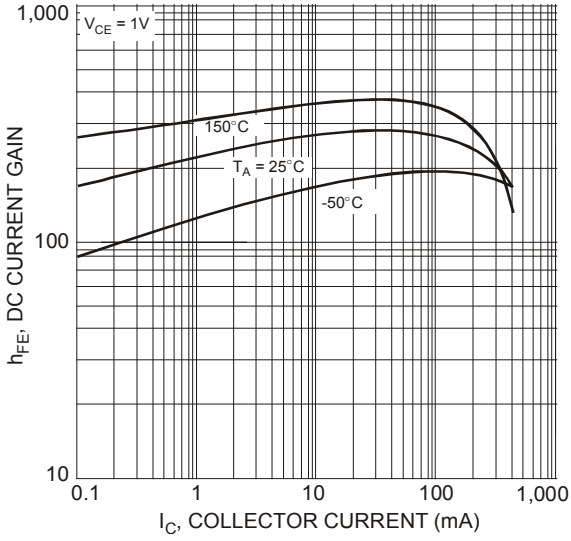
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)



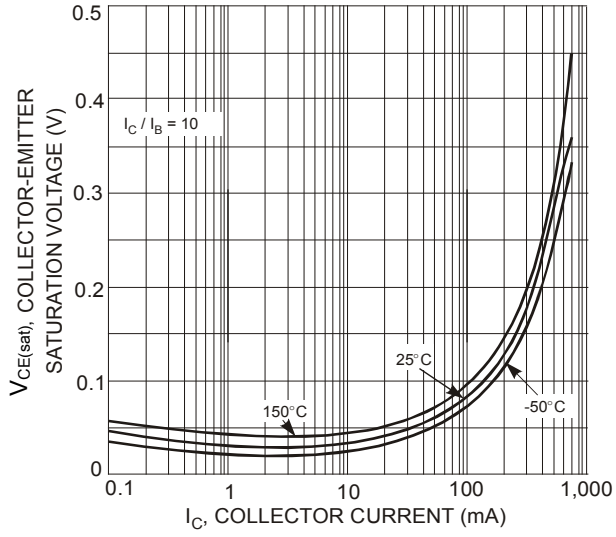
I_C v V_{CE}



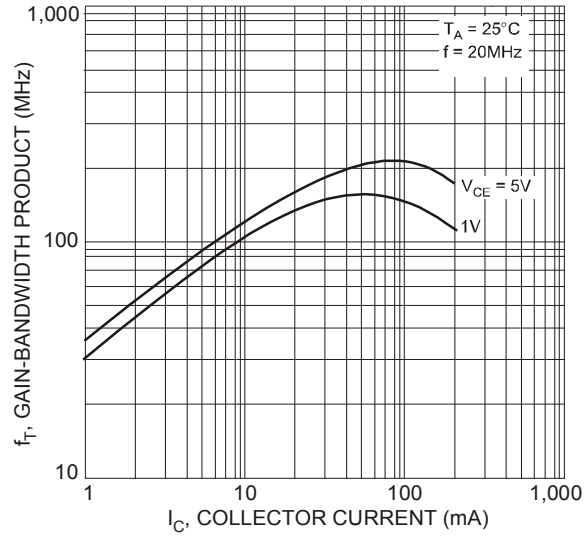
I_C v V_{CE}



h_{FE} v I_C



$V_{CE(sat)}$ v I_C



f_T v I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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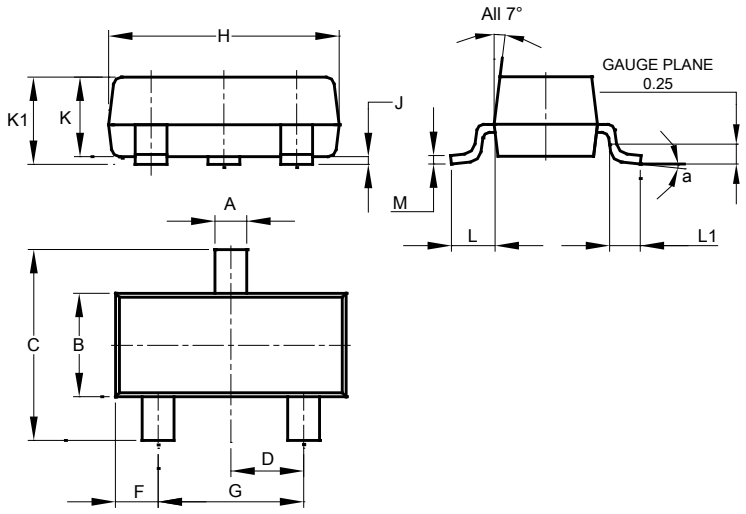

SOT23			
Dim	**Min**	**Max**	**Typ**
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

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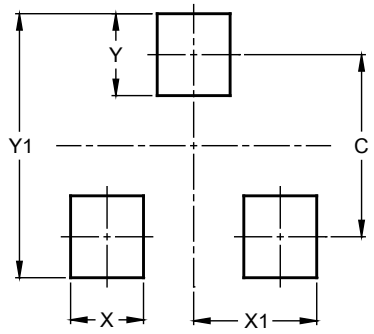

Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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